

CMDSH2-4L

SURFACE MOUNT
HIGH CURRENT, LOW V_F
SILICON SCHOTTKY DIODE



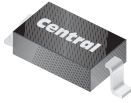
www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMDSH2-4L is a HIGH CURRENT, LOW V_F 40 volt Schottky diode packaged in a space saving SOD-323 surface mount case. This **SUPERmini™** device has been designed for small signal general purpose applications when small size and operational efficiency are prime requirements.

MARKING CODE: S2L

SUPERmini™



SOD-323 CASE

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Peak Repetitive Reverse Voltage
Continuous Forward Current
Peak Forward Surge Current, $t_p=1.0\text{ms}$
Power Dissipation
Operating and Storage Junction Temperature
Thermal Resistance

SYMBOL

V_{RRM} 40
 I_F 200
 I_{FSM} 1.0
 P_D 250
 T_J, T_{stg} -65 to +150
 θ_{JA} 500

UNITS

V
mA
A
mW
 $^\circ\text{C}$
 $^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

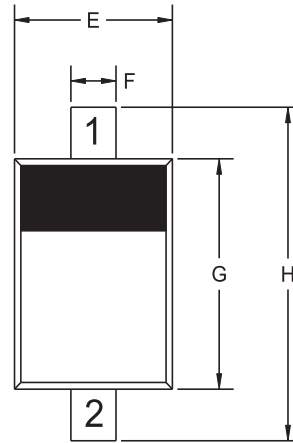
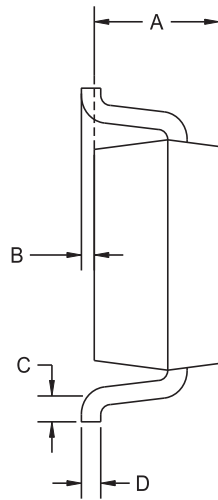
SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_R	$V_R=20\text{V}$		11	50	μA
BV_R	$I_R=100\mu\text{A}$	40	53		V
V_F	$I_F=10\text{mA}$		0.24	0.325	V
V_F	$I_F=100\text{mA}$		0.35	0.4	V
V_F	$I_F=200\text{mA}$		0.42	0.5	V
C_T	$V_R=4.0\text{V}, f=1.0\text{MHz}$		8.5	10	pF
t_{rr}	$I_F=I_R=10\text{mA}, I_{rr}=1.0\text{mA}, R_L=100\Omega$		4.0	5.0	ns

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SOD-323 CASE - MECHANICAL OUTLINE



R4

LEAD CODE:

- 1) CATHODE
- 2) ANODE

MARKING CODE: S2L

SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.031	0.039	0.80	1.00
B	0.000	0.004	0.00	0.10
C	0.008	-	0.20	-
D	0.004	0.007	0.11	0.19
E	0.045	0.053	1.15	1.35
F	-	0.014	-	0.35
G	0.063	0.071	1.60	1.80
H	0.094	0.102	2.40	2.60

SOD-323 (REV: R4)

R2 (8-January 2010)